

# MOS INTEGRATED CIRCUIT $\mu$ PD16808

# MONOLITHIC DUAL H BRIDGE DRIVER CIRCUIT

### DESCRIPTION

The  $\mu$ PD16808 is a monolithic dual H bridge driver circuit which employing N-channel power MOS FETs for its driver stage. By using the power MOS FETs for the output stage, saturation voltage and power consumption are substantially improved as compared with conventional driver circuits that use bipolar transistors.

Because the dual H bridge driver circuits at the output stage are independent of each other, this IC is ideal as the driver circuit for a 1- to 2-phase excitation bipolar driving stepping motor for the head actuator of an FDD.

### FEATURES

· Low ON resistance (sum of ON resistors of top and bottom FETs)

Ron1 = 1.0  $\Omega$  TYP. (Vm = 5.0 V)

Ron2 = 1.5  $\Omega$  TYP. (Vm = 12.0 V)

- Low current consumption: Ibb = 0.4 mA TYP.
- · Four input modes independently controlling dual H bridge drivers (with 1- to 2-phase excitation selected)
- Motor voltage 12 V/5 V compatible
- Compact surface mount package: 20-pin plastic SOP (300 mil)

### PIN CONFIGURATION (Top View)



### ORDERING INFORMATION

Part Number	Package
μPD16808GS	20-pin plastic SOP (300 mil)

### **BLOCK DIAGRAM**



----- Connected in diffusion layer

### **FUNCTION TABLE**

Excitation Direction	IN <sub>1</sub>	IN2	INз	IN4	H₁	H <sub>2</sub>
	L	L	L	L	S	S
H <sub>2</sub> R	L	L	L	Н	S	R
H <sub>2</sub> F	L	L	Н	L	S	F
	L	L	Н	Н	S	S
H₁R	L	Н	L	L	R	S
<3>	L	Н	L	Н	R	R
<2>	L	Н	Н	L	R	F
H₁R	L	Н	Н	Н	R	S
H₁F	Н	L	L	L	F	S
<4>	Н	L	L	Н	F	R
<1>	Н	L	Н	L	F	F
H₁F	Н	L	н	Н	F	S
	Н	Н	L	L	S	S
H <sub>2</sub> R	Н	Н	L	Н	S	R
H <sub>2</sub> F	Н	Н	Н	L	S	F
	Н	Н	Н	Н	S	S

### • With 1- to 2-phase excitation selected (SEL = High)



### • With 2-phase excitation selected (SEL = Low)

Excitation Direction	IN <sub>1</sub>	INз	IN4	IN2	H1	H <sub>2</sub>
<1>	Н	н	×	н	F	F
<2>	L	Н	×	Н	R	F
<3>	L	L	×	н	R	R
<4>	Н	L	×	Н	F	R
_	×	×	×	L	Stop	
F: Forward	R: Re	everse	S:	Stop	×: Don't ca	

<u>OF</u>F

ON

For the excitation waveform timing chart, refer to **APPLICATION CIRCUIT EXAMPLE**.

OFF

٥N



omol∳B

ON

OFF



٧м





### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25 $^{\circ}$ C)

Parameter	Symbol	Rating	Unit
Supply voltage (motor block)	VM	-0.5 to +15	V
Supply voltage (control block)	Vdd	-0.5 to +7	V
Power dissipation	Pd1	1.0 <sup>Note 1</sup>	W
	Pd2	1.25 <sup>Note 2</sup>	
Instantaneous H bridge driver current	l⊳ (pulse)	±1.0 <sup>Note 2, 3</sup>	A
Input voltage	VIN	-0.5 to V <sub>DD</sub> + 0.5	V
Operating temperature range	TA	0 to 60	°C
Operation junction temperature	T <sub>jMAX</sub> .	150	°C
Storage temperature range	Tstg	-55 to +125	°C

### Notes 1. IC only

- **2.** When mounted on a printed circuit board  $(100 \times 100 \times 1 \text{ mm}, \text{ glass epoxy})$
- **3.**  $t \le 5$  ms, Duty  $\le 40$  %



### Pd – TA Characteristics

### **RECOMMENDED OPERATING CONDITIONS**

Paramete	Symbol	MIN.	TYP.	MAX.	Unit	
Supply voltage (motor block)		Vм	4.0	5.0	13.2	V
Supply voltage (control block)		Vdd	4.0	5.0	6.0	V
H bridge driver currentNote	1-/2-phase excitation	ldr			±600	mA
V <sub>M</sub> = 5.0 V 2-phase excitation					±450	
Charge pump capacitance		C1 to C3	5		20	nF
Operating temperature		TA	0		60	°C

**Note** When mounted on a printed circuit board ( $100 \times 100 \times 1$  mm, glass epoxy)

### ELECTRICAL SPECIFICATIONS (Within recommended operating conditions unless otherwise specified)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
OFF V <sub>M</sub> pin current	Ім	$V_{M} = 6.0 \text{ V}, V_{DD} = 6.0 \text{ V}^{Note 1}$			1.0	μΑ
		$V_{M} = 13.2 \text{ V}, V_{DD} = 6.0 \text{ V}^{Note 1}$			1.0	mA
VDD pin current	ldd	Note 2		0.4	1.0	mA
Control pin high-level input	Ін	$T_A = 25 \ ^{\circ}C, \ V_{IN} = V_{DD}$			1.0	μA
current		$0 \leq T_{\text{A}} \leq 60 \ ^{\circ}\text{C}, \ V_{\text{IN}} = V_{\text{DD}}$			2.0	
Control pin low-level input	lı∟	$T_A = 25 \ ^\circ C, \ V_{IN} = 0 \ V$			-0.18	mA
current		$0 \leq T_A \leq 60 \ ^\circ C, \ V_{IN} = 0 \ V$			-0.25	
Control pin input pull-up	Rin	T <sub>A</sub> = 25 °C	35	50	65	kΩ
resistance		$0 \le T_A \le 60 \ ^\circ C$	25		75	
Control pin high-level input voltage	Vih		3.0		Vdd + 0.3	V
Control pin low-level input voltage	VIL		-0.3		0.8	V
H bridge circuit ON	Ron1	Vdd = 5 V, Vm = 5 V		1.0	2.0	Ω
resistance <sup>Note 3</sup>	Ron2	Vdd = 5 V, Vm = 12 V		1.5	3.0	Ω
Ron relative accuracy	$\Delta R$ on1	Excitation direction <2>, <4>Note 4			±5	%
	$\Delta R$ on2	Excitation direction <1>, <3>			±10	
Charge pump circuit (V <sub>G</sub> ) turn-ON time	Tong	Vdd = 5 V, Vm = 5 V		0.2	1.0	ms
H bridge circuit turn-ON time	Толн	$C_1 = C_2 = C_3 = 10 \text{ nF}$			5	μs
H bridge circuit turn-OFF time	Тоггн	R <sub>M</sub> = 20 Ω			5	μs

Notes 1. Control pins (IN1, IN2, IN3, IN4): low

2. Control pins (IN1, IN2, IN3, IN4): high

3. Sum of ON resistances of top and bottom transistors

4. For the excitation direction, refer to FUNCTION TABLE.

### CHARACTERISTIC CURVES



50

100

Operation junction temperature  $T_j$  (°C)

150

Ron vs. Tj Characteristics

# APPLICATION CIRCUIT EXAMPLE

Connection with 1-chip FDD LSI  $\mu$ PC2100AGF (With 1- to 2-phase excitation selected)





•



The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

 $\boldsymbol{\infty}$ 

# 20 PIN PLASTIC SOP (300 mil)









ITEM	MILLIMETERS	INCHES
Α	13.00 MAX.	0.512 MAX.
В	0.78 MAX.	0.031 MAX.
С	1.27 (T.P.)	0.050 (T.P.)
D	$0.40^{+0.10}_{-0.05}$	$0.016^{+0.004}_{-0.003}$
E	0.1±0.1	0.004±0.004
F	1.8 MAX.	0.071 MAX.
G	1.55	0.061
Н	7.7±0.3	0.303±0.012
I	5.6	0.220
J	1.1	0.043
К	$0.20^{+0.10}_{-0.05}$	$0.008^{+0.004}_{-0.002}$
L	0.6±0.2	$0.024^{+0.008}_{-0.009}$
М	0.12	0.005
Ν	0.10	0.004
Р	3°+7° -3°	3°+7° -3°

P20GM-50-300B, C-4

### NOTE

Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

### **RECOMMENDED SOLDERING CONDITIONS**

It is recommended to solder this product under the conditions described below.

For soldering methods and conditions other than those listed below, consult NEC.

### Surface mount type

For the details of the recommended soldering conditions of this type, refer to **Semiconductor Device Mounting Technology Manual (C10535E)**.

Soldering Method	Soldering Conditions	Symbol of Recommended Soldering
Infrared reflow	Peak package temperature: 230 °C, Time: 30 seconds MAX. (210 °C MIN.), Number of times: 1, Number of days: None <sup>Note</sup>	IR30-00
VPS	Peak package temperature: 215 °C, Time: 40 seconds MAX. (200 °C MIN.), Number of times: 1, Number of days: None <sup>Note</sup>	VP15-00
Wave soldering	Solder bath temperature: 260 °C MAX., Time: 10 seconds MAX., Number of times: 1, Number of days: None <sup>Note</sup>	WS60-00
Partial heating	Pin temperature: 300 °C MAX., Time: 10 seconds MAX., Number of days: None <sup>Note</sup>	_

Note The number of storage days at 25 °C, 65 % RH after the dry pack has been opened

Caution Do not use two or more soldering methods in combination (except partial heating).

[MEMO]

[MEMO]

No part of this document may be copied or reproduced in any form or by any means without the prior written consent of NEC Corporation. NEC Corporation assumes no responsibility for any errors which may appear in this document.

NEC Corporation does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from use of a device described herein or any other liability arising from use of such device. No license, either express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Corporation or others.

While NEC Corporation has been making continuous effort to enhance the reliability of its semiconductor devices, the possibility of defects cannot be eliminated entirely. To minimize risks of damage or injury to persons or property arising from a defect in an NEC semiconductor device, customers must incorporate sufficient safety measures in its design, such as redundancy, fire-containment, and anti-failure features.

NEC devices are classified into the following three quality grades:

"Standard", "Special", and "Specific". The Specific quality grade applies only to devices developed based on a customer designated "quality assurance program" for a specific application. The recommended applications of a device depend on its quality grade, as indicated below. Customers must check the quality grade of each device before using it in a particular application.

- Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
- Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
- Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

The quality grade of NEC devices is "Standard" unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact an NEC sales representative in advance.

Anti-radioactive design is not implemented in this product.